



N-Channel Super-junction MOSFET Gen III

MOSFET

Metal Oixde Semiconductor Field Effect Transistor

650V Super-junction Gen III

650V Super-junction Gen III Power Transistor

HRD65T160x Data Sheet

Rev. 2020 V1.1

矽源特科技
ChipSourceTek



650V Super-junction Power MOSFET Gen III

<p>Description</p> <p>650V Super-junction MOSFET Gen III</p> <p>Super-junction MOSFET Gen III is designed by HR-Micro Semiconductor Company, according to the SJ principle. This device provides an excellent Gate charge and $R_{DS(on)}$, which leads to extremely low commutation and conduction losses. So it is very suitable for AC/DC power conversion, Laptop adapter, Lighting, and industrial power applications.</p>																																																	
<p>Features</p> <ul style="list-style-type: none"> • Very low FOM $R_{DS(on)} \times Q_g$ • 100% avalanche tested • Easy to use/drive • RoHS compliant 																																																	
<p>Applications</p> <ul style="list-style-type: none"> • Switch Mode Power Supply (SMPS) • Uninterruptible Power Supply (UPS) • Power Factor Correction (PFC) • Charger 	<p>Key Performance Parameters</p> <table border="1"> <thead> <tr> <th>Parameter</th> <th>Value</th> <th>Unit</th> </tr> </thead> <tbody> <tr> <td>$V_{DS} @ T_{j,max}$</td> <td>700</td> <td>V</td> </tr> <tr> <td>$R_{DS(on),max}$</td> <td>0.16</td> <td>Ω</td> </tr> <tr> <td>$Q_{g,typ}$</td> <td>32.9</td> <td>nC</td> </tr> <tr> <td>I_D</td> <td>21</td> <td>A</td> </tr> <tr> <td>$I_{D,pulse}$</td> <td>63</td> <td>A</td> </tr> <tr> <td>$E_{OSS} @ 400V$</td> <td>4.14</td> <td>μJ</td> </tr> <tr> <td>Body Diode di_f/dt</td> <td>500</td> <td>A/μs</td> </tr> </tbody> </table> <p>Device Marking and Package Information</p> <table border="1"> <thead> <tr> <th>Device</th> <th>Package</th> <th>Marking</th> </tr> </thead> <tbody> <tr> <td>HRD65T160B</td> <td>TO-263</td> <td>D65T160B</td> </tr> <tr> <td>HRD65T160D</td> <td>TO-252</td> <td>D65T160D</td> </tr> <tr> <td>HRD65T160F</td> <td>TO-220F</td> <td>D65T160F</td> </tr> <tr> <td>HRD65T160L</td> <td>TO-262</td> <td>D65T160L</td> </tr> <tr> <td>HRD65T160P</td> <td>TO-220</td> <td>D65T160P</td> </tr> <tr> <td>HRD65T160U</td> <td>TO-251</td> <td>D65T160U</td> </tr> <tr> <td>HRD65T160W</td> <td>TO-247</td> <td>D65T160W</td> </tr> </tbody> </table>	Parameter	Value	Unit	$V_{DS} @ T_{j,max}$	700	V	$R_{DS(on),max}$	0.16	Ω	$Q_{g,typ}$	32.9	nC	I_D	21	A	$I_{D,pulse}$	63	A	$E_{OSS} @ 400V$	4.14	μJ	Body Diode di_f/dt	500	A/ μs	Device	Package	Marking	HRD65T160B	TO-263	D65T160B	HRD65T160D	TO-252	D65T160D	HRD65T160F	TO-220F	D65T160F	HRD65T160L	TO-262	D65T160L	HRD65T160P	TO-220	D65T160P	HRD65T160U	TO-251	D65T160U	HRD65T160W	TO-247	D65T160W
Parameter	Value	Unit																																															
$V_{DS} @ T_{j,max}$	700	V																																															
$R_{DS(on),max}$	0.16	Ω																																															
$Q_{g,typ}$	32.9	nC																																															
I_D	21	A																																															
$I_{D,pulse}$	63	A																																															
$E_{OSS} @ 400V$	4.14	μJ																																															
Body Diode di_f/dt	500	A/ μs																																															
Device	Package	Marking																																															
HRD65T160B	TO-263	D65T160B																																															
HRD65T160D	TO-252	D65T160D																																															
HRD65T160F	TO-220F	D65T160F																																															
HRD65T160L	TO-262	D65T160L																																															
HRD65T160P	TO-220	D65T160P																																															
HRD65T160U	TO-251	D65T160U																																															
HRD65T160W	TO-247	D65T160W																																															



Absolute Maximum Ratings $T_C = 25^\circ\text{C}$, unless otherwise noted			
Parameter	Symbol	Value	Unit
Drain-Source voltage($V_{GS}=0\text{V}$)	V_{DS}	650	V
Continuous Drain Current ¹⁾	I_D	$T_C = 25^\circ\text{C}$	21
		$T_C = 100^\circ\text{C}$	12.6
Pulsed Drain Current ²⁾	$I_{D,pulse}$	63	A
Gate-Source Voltage	V_{GS}	± 30	V
Single Pulse Avalanche Energy	E_{AS}	497	mJ
Repetitive Avalanche Energy	E_{AR}	0.75	mJ
Avalanche Current	I_{AR}	4.1	A
MOSFET dv/dt Ruggedness, $V_{DS} = 0 \dots 480\text{V}$	dv/dt	50	V/ns
Power Dissipation For TO-263、TO-252、TO-262、TO-220、TO-251、TO-247	P_D	176	W
Power Dissipation For TO-220F		34	
Continuous Diode Forward Current	I_S	17.9	A
Diode Pulsed Current ²⁾	$I_{S,pulse}$	63	
Reverse Diode dv/dt ³⁾	dv/dt	15	V/ns
Maximum Diode Commutation Speed	di/dt	500	A/ μs
Operating Junction and Storage Temperature Range	T_J, T_{stg}	-55~+150	$^\circ\text{C}$

Thermal Resistance For TO-263、TO-252、TO-262、TO-220、TO-251、TO-247			
Parameter	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case	R_{thJC}	0.71	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction-to-Ambient	R_{thJA}	62	

Thermal Resistance For TO-220F			
Parameter	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case	R_{thJC}	3.67	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction-to-Ambient	R_{thJA}	80	

Notes

- 1) Limited by maximum junction temperature.
- 2) Repetitive Rating: Pulse width limited by maximum junction temperature.
- 3) Identical low side and high side switch with identical R_G .



Electrical Characteristics $T_J = 25^\circ\text{C}$, unless otherwise noted						
Parameter	Symbol	Test Conditions	Value			Unit
			Min.	Typ.	Max.	
Static Characteristics						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu A$	650	--	--	V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 650V$ $V_{GS} = 0V, T_J = 25^\circ\text{C}$	--	--	1	μA
		$V_{DS} = 650V$, $V_{GS} = 0V, T_J = 150^\circ\text{C}$	--	--	100	
Gate-Source Leakage Current	I_{GSS}	$V_{GS} = \pm 30V$	--	--	± 100	nA
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu A$	3	3.5	4	V
Drain-Source On-State-Resistance	$R_{DS(on)}$	$V_{GS} = 10V, I_D = 10.5A$	--	0.13	0.16	Ω
Gate Resistance	R_G	$f = 1.0\text{MHz}$ open drain	--	2.7	--	Ω
Dynamic Characteristics						
Input Capacitance	C_{iss}	$V_{GS} = 0V$, $V_{DS} = 100V$ $f = 1.0\text{MHz}$	--	1517	--	μF
Output Capacitance	C_{oss}		--	51.4	--	
Reverse Transfer Capacitance	C_{rss}		--	2.3	--	
Total Gate Charge	Q_g	$V_{DD} = 520V, I_D = 21A$ $V_{GS} = 10V$	--	32.9	--	nC
Gate-Source Charge	Q_{gs}		--	9.9	--	
Gate-Drain Charge	Q_{gd}		--	9.8	--	
Gate Plateau Voltage	$V_{Plateau}$		--	5.67	--	
Turn-on Delay Time	$t_{d(on)}$	$V_{DD} = 400V, I_D = 21A$ $R_G = 15\Omega, V_{GS} = 10V$	--	13	--	ns
Turn-on Rise Time	t_r		--	13	--	
Turn-off Delay Time	$t_{d(off)}$		--	96	--	
Turn-off Fall Time	t_f		--	8	--	
Drain-Source Body Diode Characteristics						
Body Diode Forward Voltage	V_{SD}	$T_J = 25^\circ\text{C}, I_{SD} = 10.5A$, $V_{GS} = 0V$	--	0.9	1.2	V
Reverse Recovery Time	t_{rr}	$V_R = 400V$ $I_F = 10.5A, di_F/dt = 100A/\mu s$	--	300	--	ns
Reverse Recovery Charge	Q_{rr}		--	3.3	--	μC
Peak Reverse Recovery Current	I_{rrm}		--	22	--	A



Typical Characteristics $T_J = 25^\circ\text{C}$, unless otherwise noted

Figure 1. Transient Thermal Impedance
For TO-263/TO-252/TO-262/TO-220/TO-251/TO247

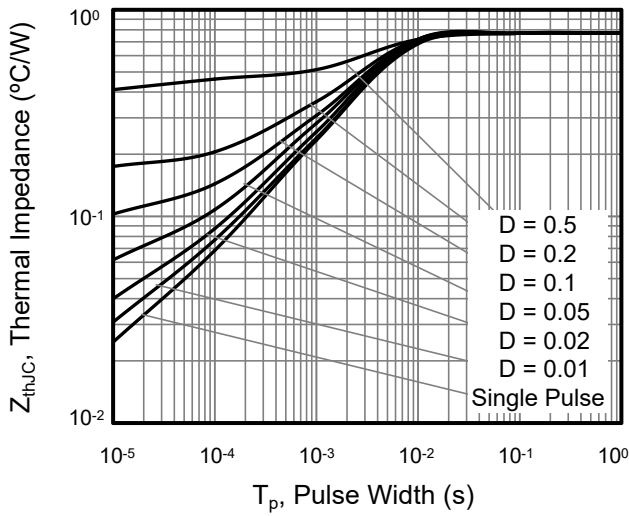


Figure 2. Transient Thermal Impedance
For TO-220F

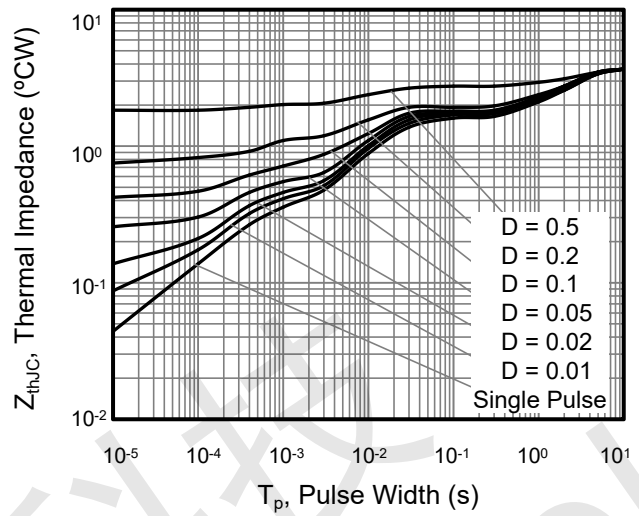


Figure 3. Safe Operation Area
For TO-263/TO-252/TO-262/TO-220/TO-251/TO-247

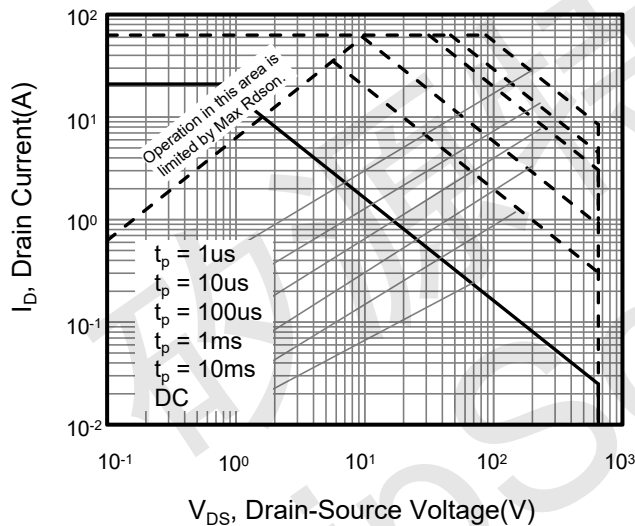


Figure 4. Safe Operation Area
For TO-220F

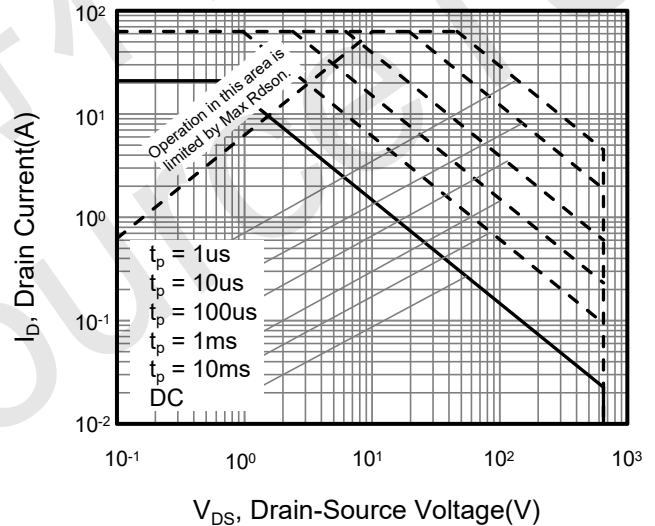


Figure 5. Output Characteristics

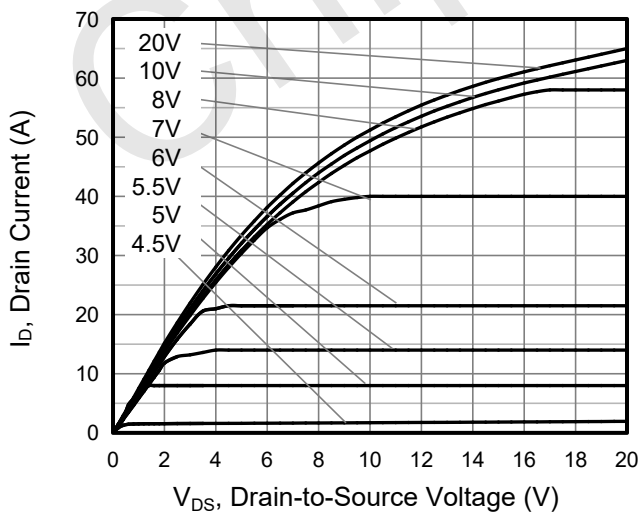
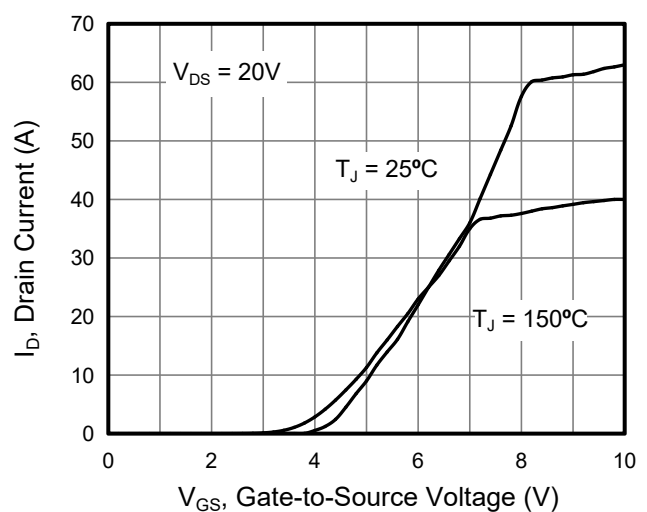


Figure 6. Transfer Characteristics





Typical Characteristics $T_J = 25^\circ\text{C}$, unless otherwise noted

Figure 7. On-Resistance vs. Drain Current

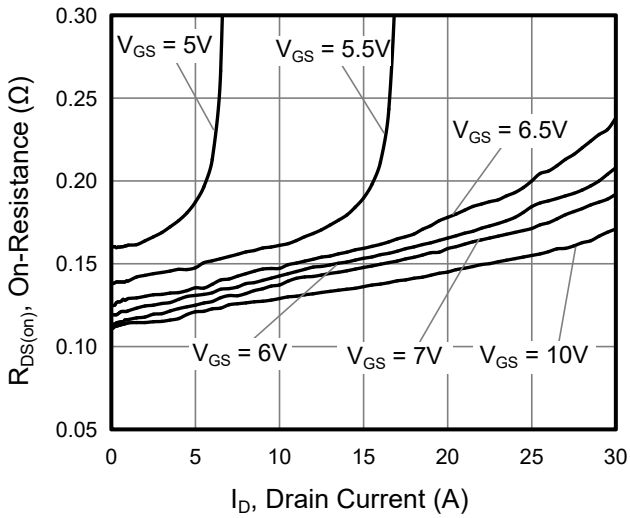


Figure 9. Gate Charge

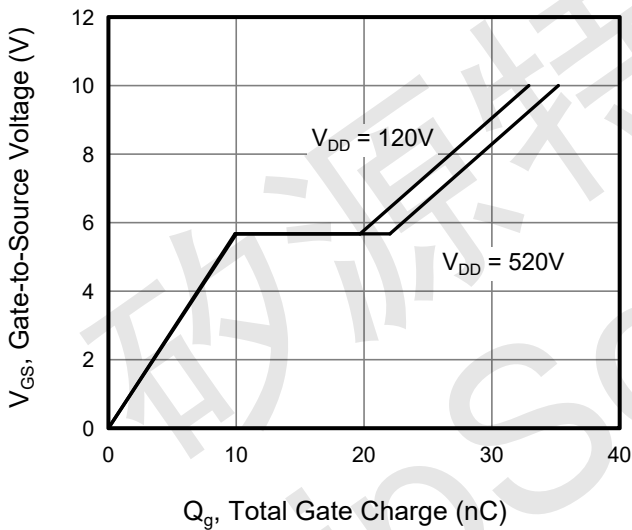


Figure 11. Typ. C_{oss} Stored Energy

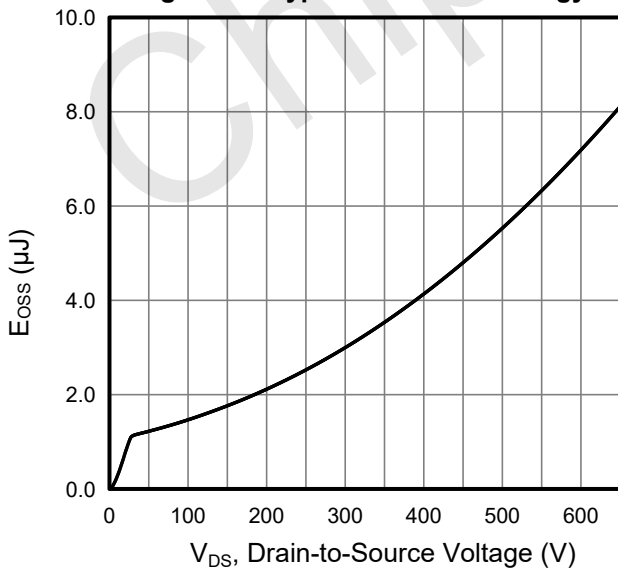


Figure 8. Capacitance

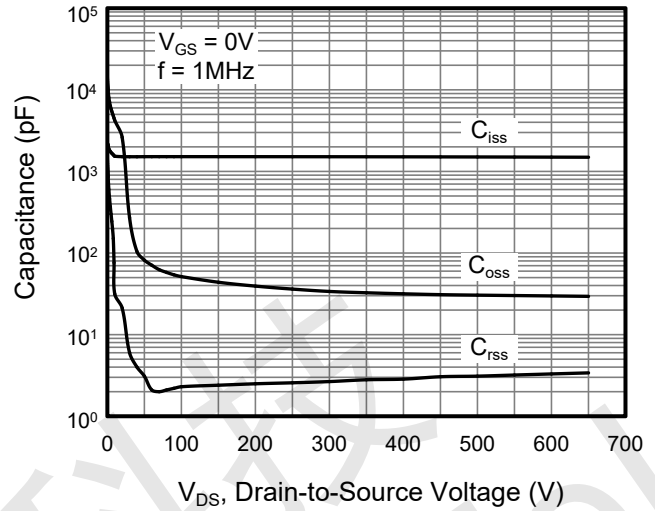


Figure 10. Body Diode Forward Voltage

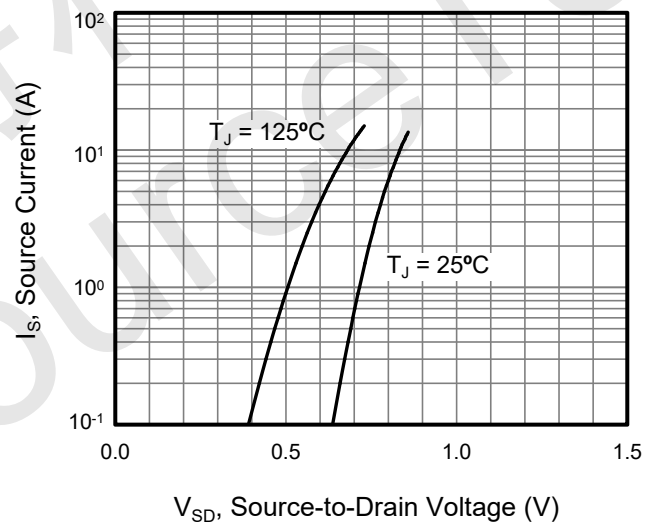
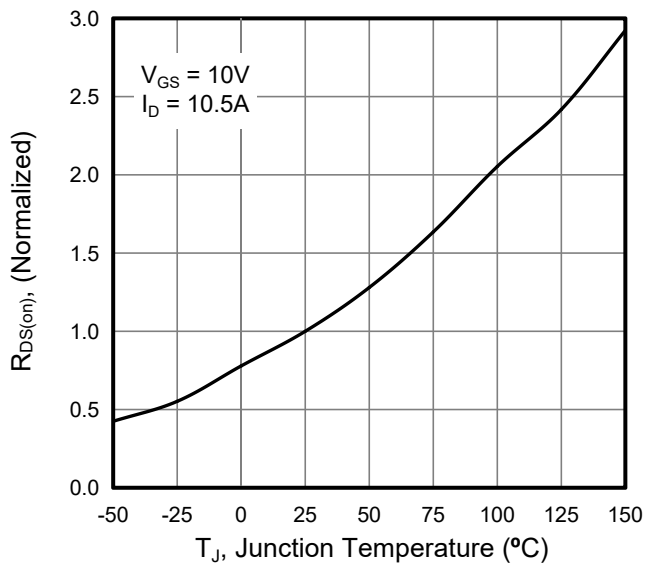


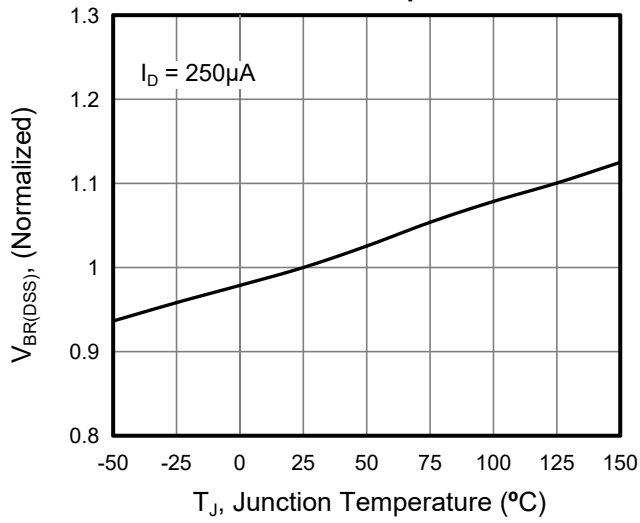
Figure 12. On-Resistance vs. Temperature





Typical Characteristics $T_J = 25^\circ\text{C}$, unless otherwise noted

Figure 13. Breakdown Voltage vs. Junction Temperature



矽源特科技
ChipSourceTek



Figure A: Gate Charge Test Circuit and Waveform

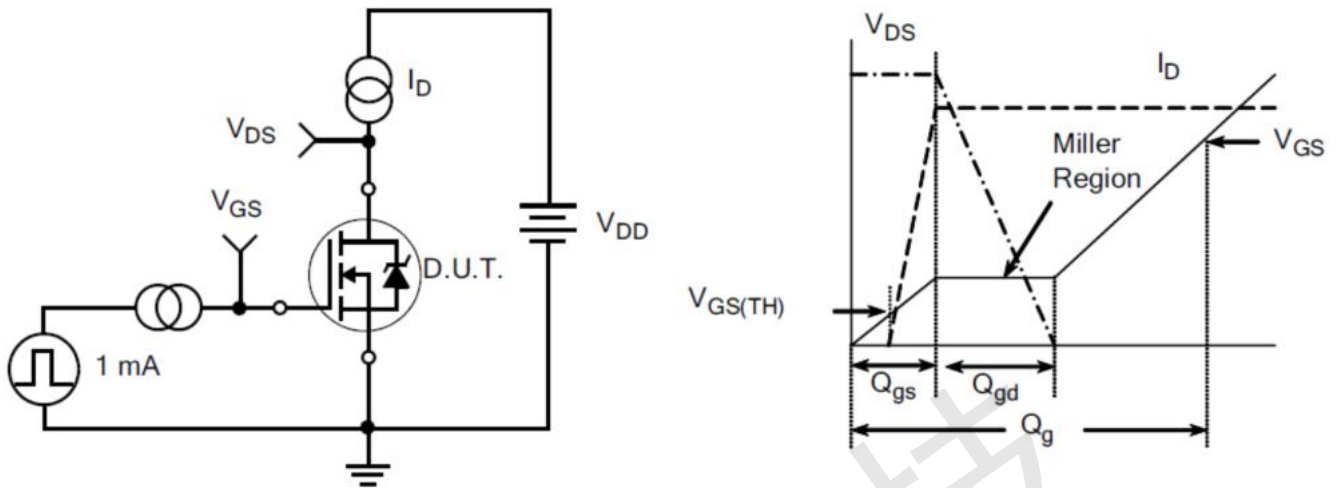


Figure B: Resistive Switching Test Circuit and Waveform

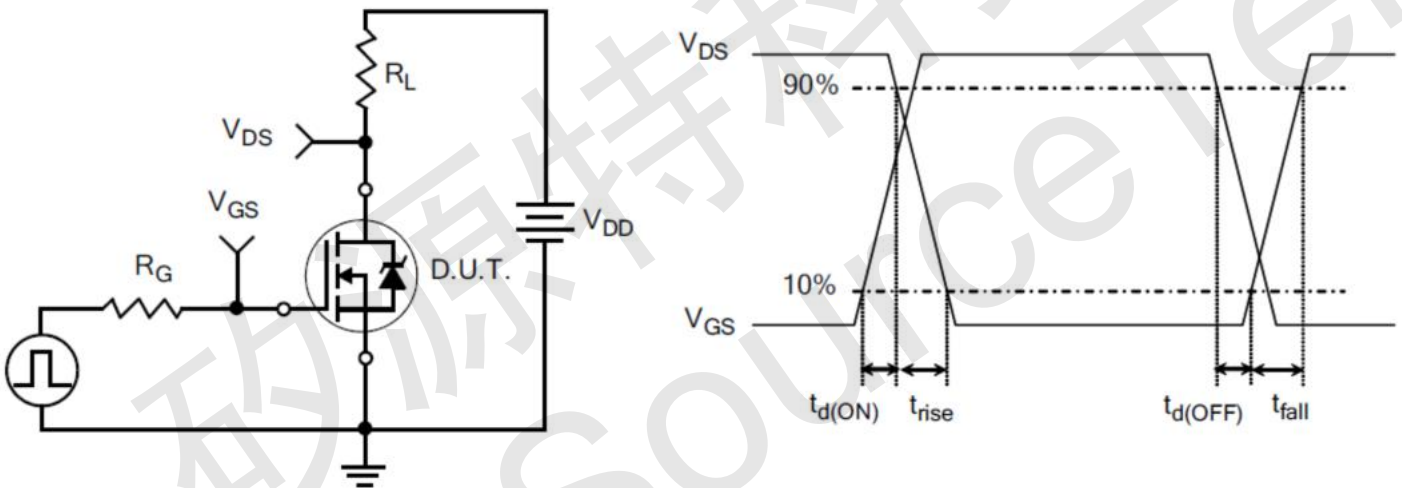
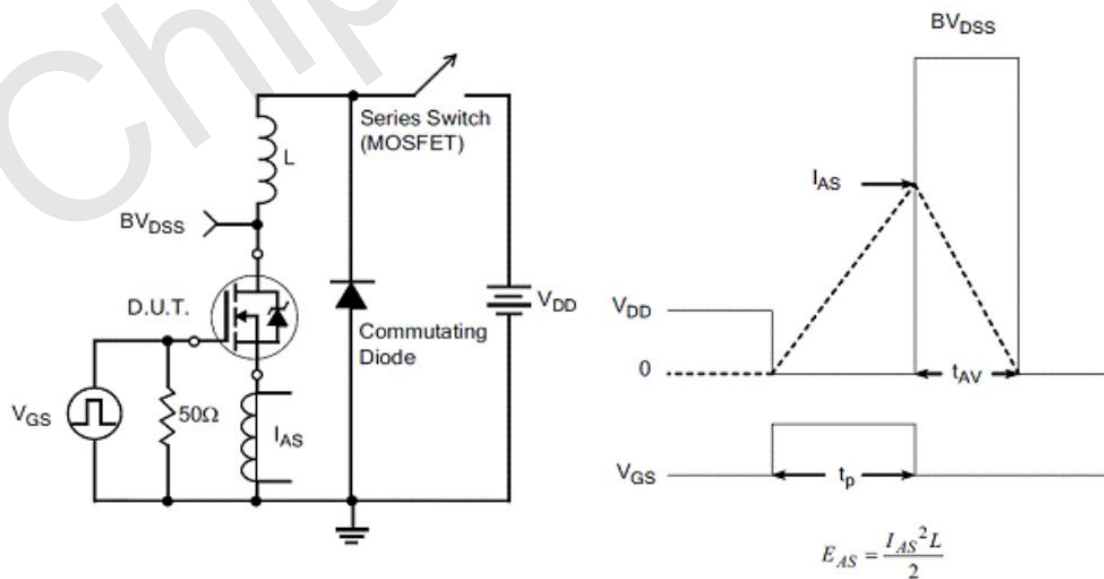
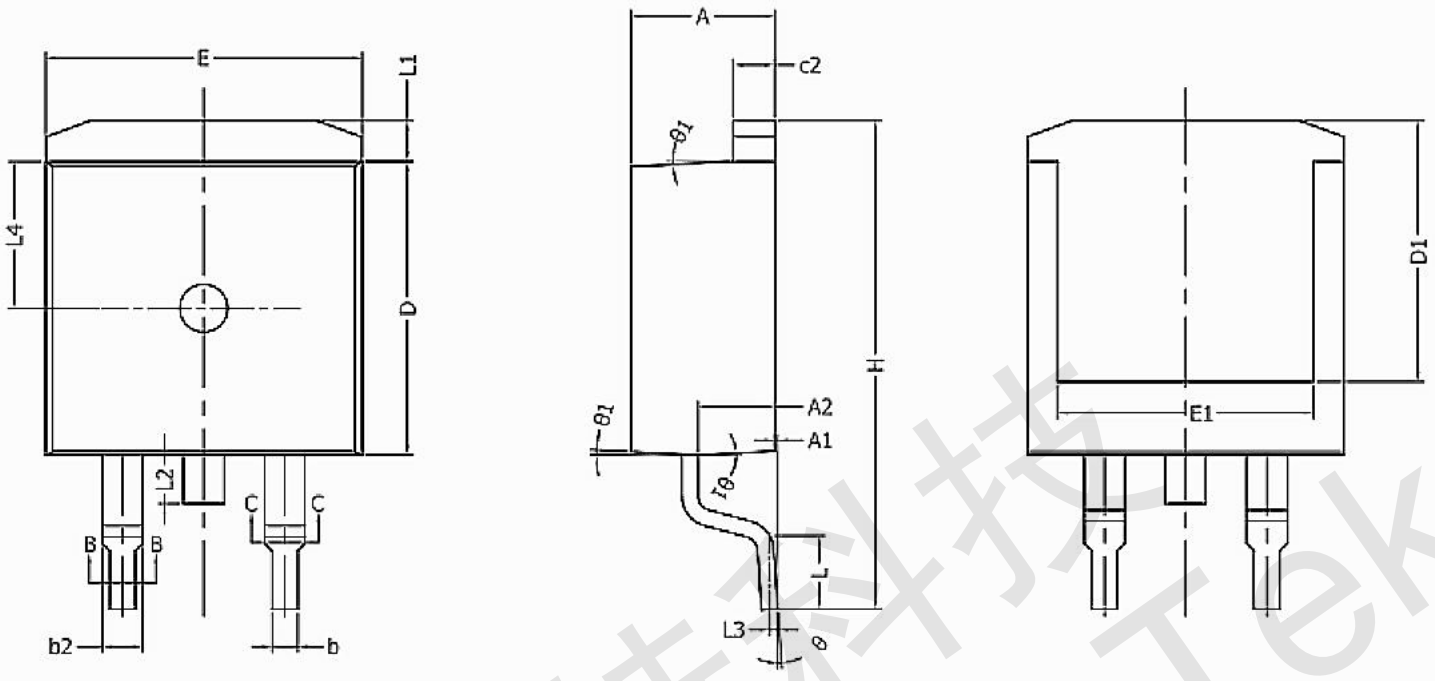


Figure C: Unclamped Inductive Switching Test Circuit and Waveform





TO-263



Unit:mm			
Symbol	Min.	Nom	Max.
A	4.40	4.50	4.60
A1	0	0.10	0.25
A2	2.20	2.40	2.60
b	0.76	---	0.89
b1	0.75	0.80	0.85
b2	1.23	---	1.37
b3	1.22	1.27	1.32
c	0.47	---	0.60
c1	0.46	0.51	0.56
c2	1.25	1.30	1.35
D	9.10	9.20	9.30

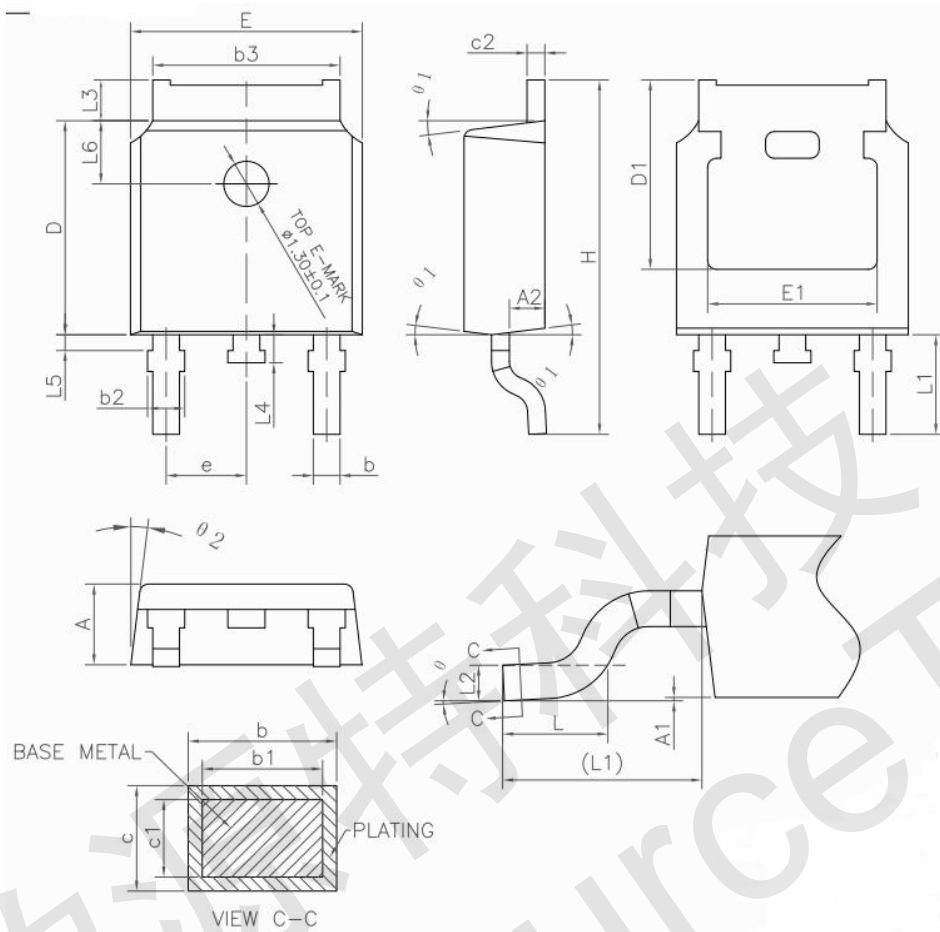
Unit:mm			
Symbol	Min.	Nom	Max.
D1	8.00	---	---
E	9.80	9.90	10.00
E1	7.80	---	---
e	2.54 BSC		
H	14.90	15.30	15.70
L	2.00	2.30	2.60
L1	1.17	1.27	1.40
L2	---	---	1.75
L3	0.25 BSC		
L4	4.60 REF		
theta	0°	---	8°
theta1	1°	3°	5°

Ordering information For TO-263

Package	Units/Tape	Tapes/ Inner Box	Units/Inner Box	Inner Box/Carton Box	Units/Carton Box
TO-263	800	1	800	10	8000



TO-252



Unit:mm			
Symbol	Min.	Nom	Max.
A	2.20	2.30	2.38
A1	0.00	-	0.20
A2	0.90	1.01	1.10
b	0.72	--	0.85
b1	0.71	0.76	0.81
b2	0.72	--	0.90
b3	5.13	5.33	5.46
c	0.47	--	0.60
c1	0.46	0.51	0.56
c2	0.47	--	0.60
D	6.00	6.10	6.20
D1	5.25	--	--
E	6.50	6.60	6.70

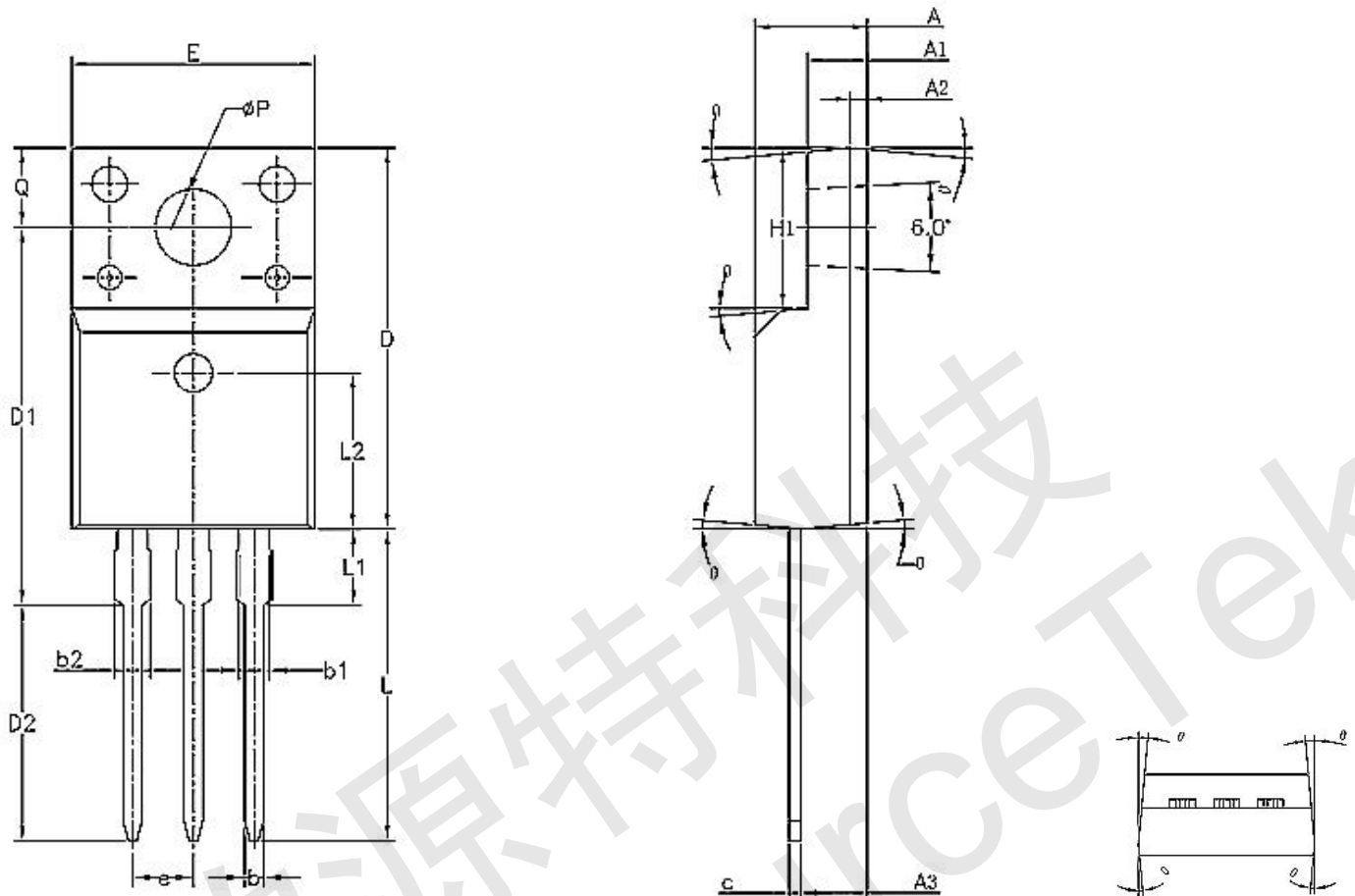
Unit:mm			
Symbol	Min.	Nom	Max.
E1	4.70	--	--
e	2.186	2.286	2.386
H	9.80	10.10	10.40
L	1.40	1.50	1.70
L1	2.90 REF		
L2	0.508 BSC		
L3	0.90	--	1.25
L4	0.60	0.80	1.00
L5	0.15	--	0.75
L6	1.80 REF		
θ	0°	-	8°
θ1	5°	7°	9°
θ2	5°	7°	9°

Ordering information For TO-252

Package	Units/Tape	Tapes/ Inner Box	Units/Inner Box	Inner Box/Carton Box	Units/Carton Box
TO-252	2500	2	5000	5	25000



TO-220F



Unit:mm			
Symbol	Min.	Nom	Max.
A	4.50	4.70	4.83
A1	2.34	2.54	2.74
A2	0.70 REF		
A3	2.56	2.76	2.93
b	0.70	---	0.90
b1	1.18	---	1.38
b2	---	---	1.47
c	0.45	0.50	0.60
D	15.67	15.87	16.07
D1	15.55	15.75	15.95

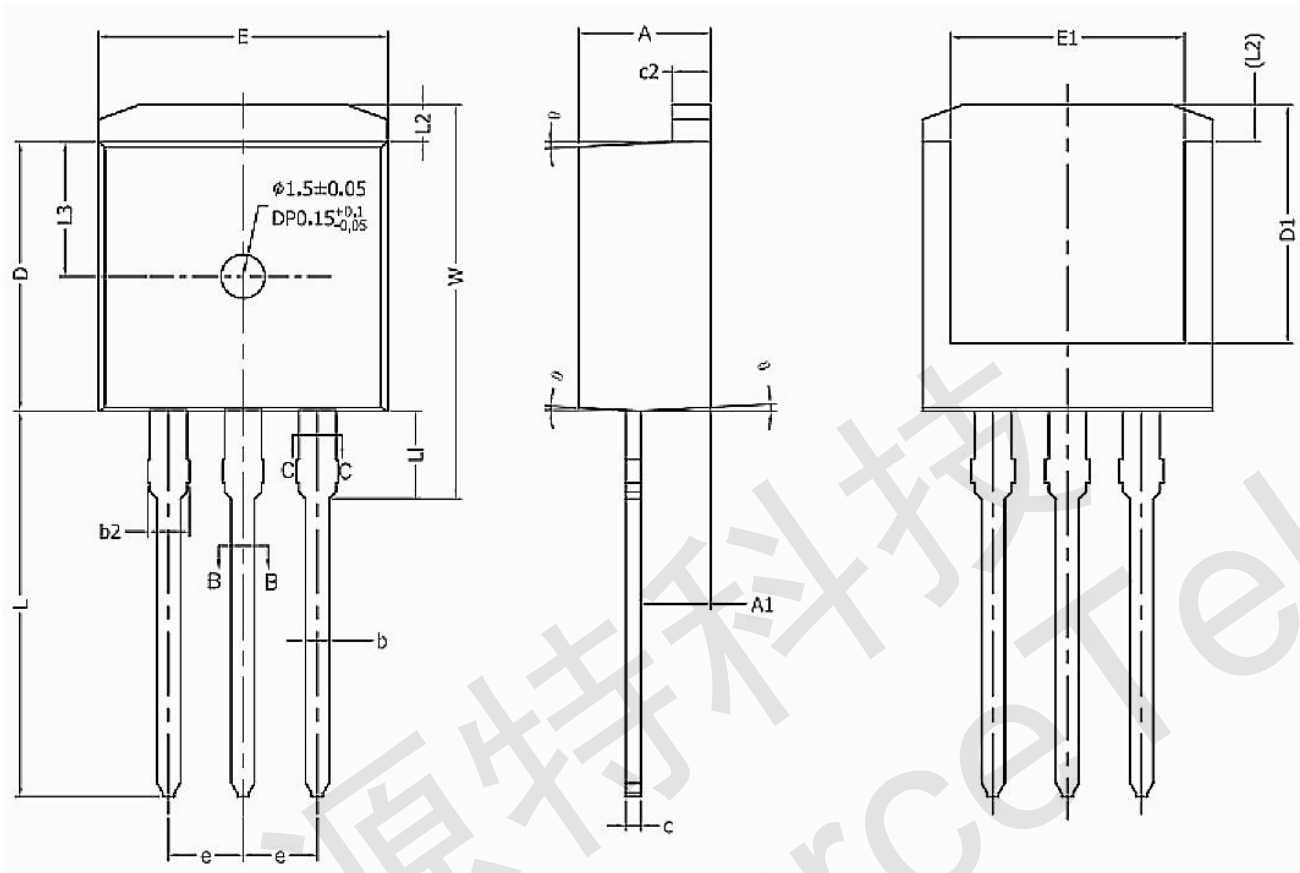
Unit:mm			
Symbol	Min.	Nom	Max.
D2	9.60	9.80	10.0
E	9.96	10.16	10.36
e	2.54 BSC		
H1	6.48	6.68	6.88
L	12.68	12.98	13.28
L1	---	---	3.50
L2	6.50 REF		
ΦP	3.08	3.18	3.28
Q	3.20	---	3.40
θ1	1°	3°	5°

Ordering information For TO-220F

Package	Units/Tube	Tubes/ Inner Box	Units/Inner Box	Inner Box/Carton Box	Units/Carton Box
TO-220F	50	40	2000	4	8000



TO-262



Unit:mm			
Symbol	Min.	Nom	Max.
A	4.40	4.50	4.60
A1	2.20	2.40	2.60
b	0.76	---	0.89
b1	0.75	0.80	0.85
b2	1.23	---	1.37
b3	1.22	1.27	1.32
c	0.47	---	0.60
c1	0.46	0.51	0.56
c2	1.25	1.30	1.35
D	9.10	9.20	9.30

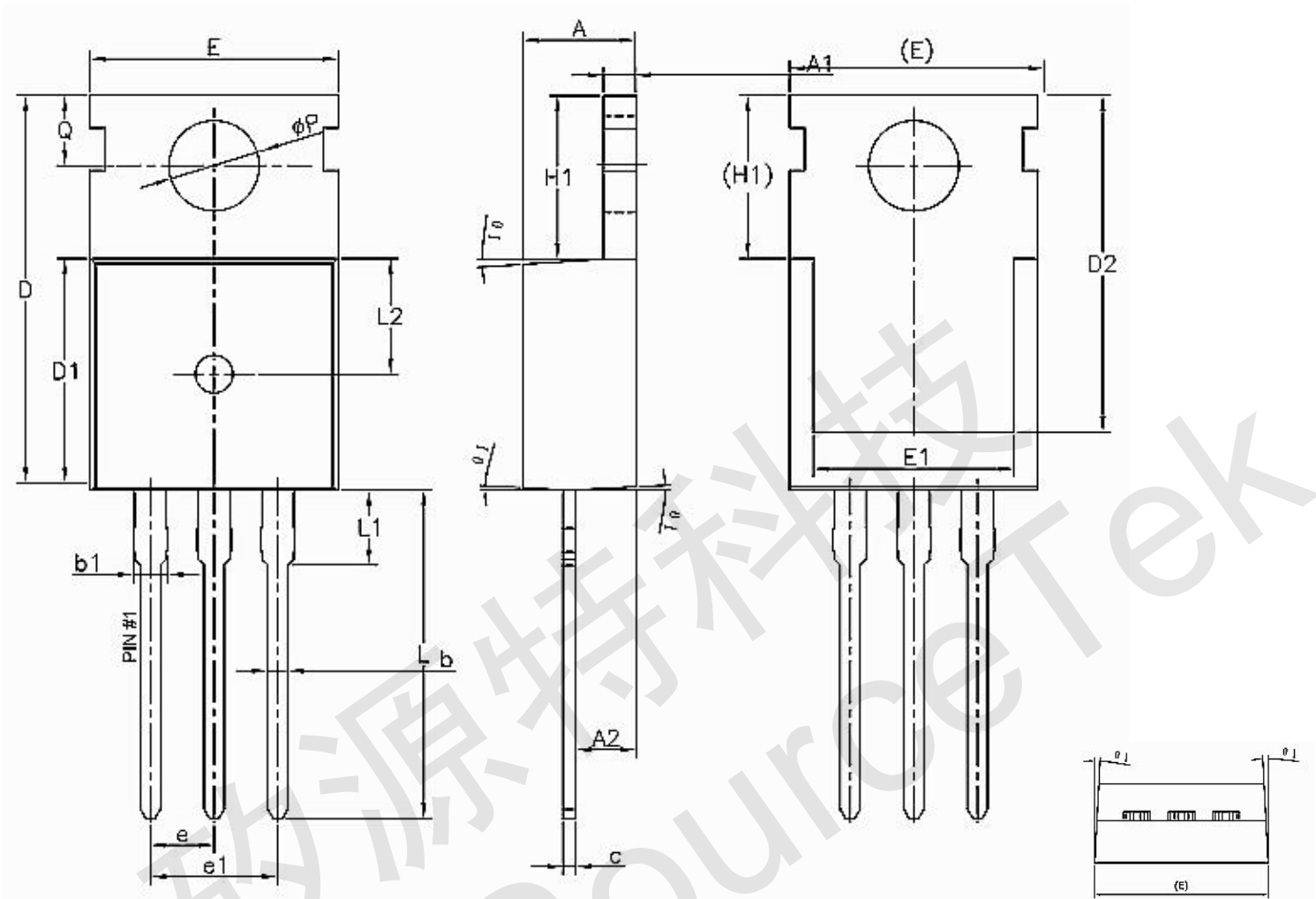
Unit:mm			
Symbol	Min.	Nom	Max.
D1	8.00	---	---
E	9.80	9.90	10.00
E1	7.80	---	---
e	2.54 BSC		
L	12.90	13.20	13.50
L1	2.80	3.00	3.20
L2	1.17	1.27	1.40
L3	4.60 REF		
W	13.25	---	14.00
theta	1°	3°	5°

Ordering information For TO-262

Package	Units/Tube	Tubes/ Inner Box	Units/Inner Box	Inner Box/Carton Box	Units/Carton Box
TO-262	50	40	2000	4	8000



TO-220



Unit:mm			
Symbol	Min.	Nom	Max.
A	4.40	4.50	4.60
A1	1.27	1.30	1.33
A2	2.30	2.40	2.50
b	0.70	---	0.90
b2	1.27	---	1.40
c	0.45	0.50	0.60
D	15.30	15.70	16.10
D1	9.10	9.20	9.30
D2	13.10	---	13.70
E	9.70	9.90	10.20

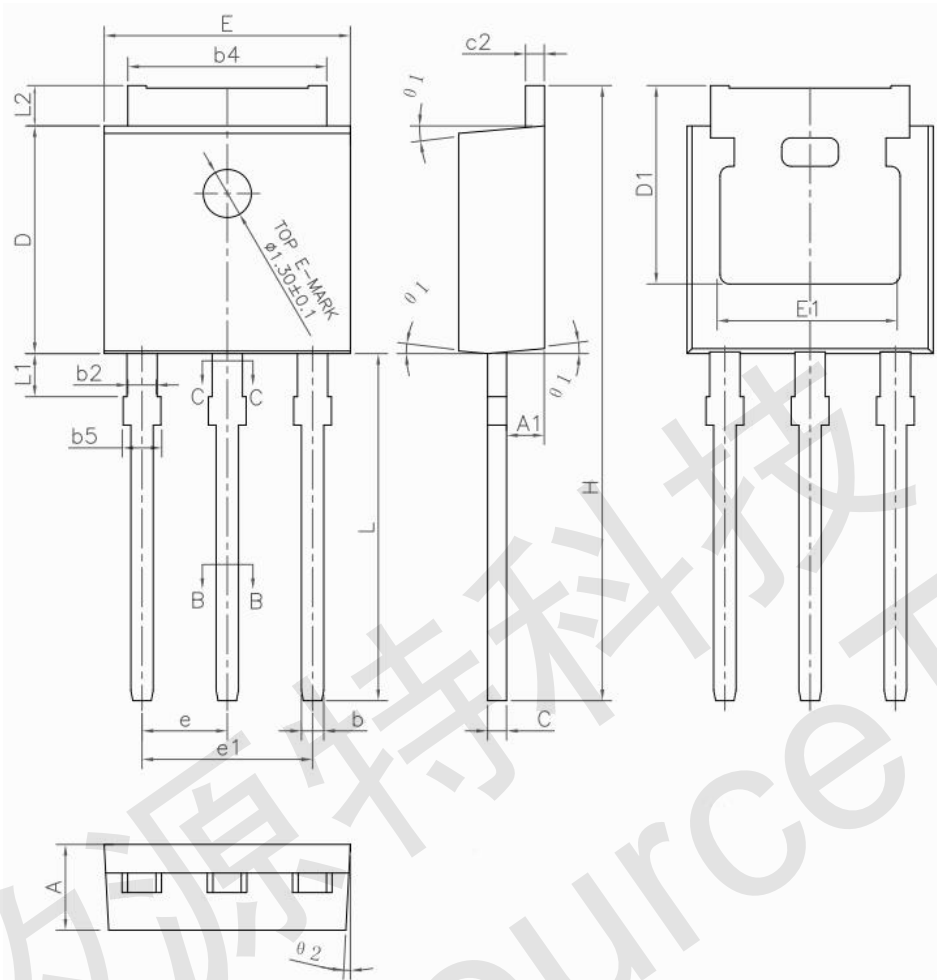
Unit:mm			
Symbol	Min.	Nom	Max.
E1	7.80	8.00	8.20
e	2.54 BSC		
e1	5.08 BSC		
H1	6.30	6.50	6.70
L	12.78	13.08	13.38
L1	---	---	3.50
L2	4.60 REF		
ΦP	3.55	3.60	3.65
Q	2.73	---	2.87
θ1	1°	3°	5°

Ordering information For TO-220

Package	Units/Tube	Tubes/ Inner Box	Units/Inner Box	Inner Box/Carton Box	Units/Carton Box
TO-220	50	40	2000	4	8000



TO-251



Unit:mm			
Symbol	Min.	Nom	Max.
A	2.20	2.30	2.35
A1	0.90	1.01	1.10
b	0.56	--	0.69
b1	0.55	0.60	0.65
b2	0.77	--	0.90
b3	0.76	0.81	0.86
b4	5.23	5.33	5.43
b5	--	--	1.05
c	0.46	--	0.59
c1	0.45	0.51	0.55
c2	0.46	--	0.59
D	6.00	6.10	6.20

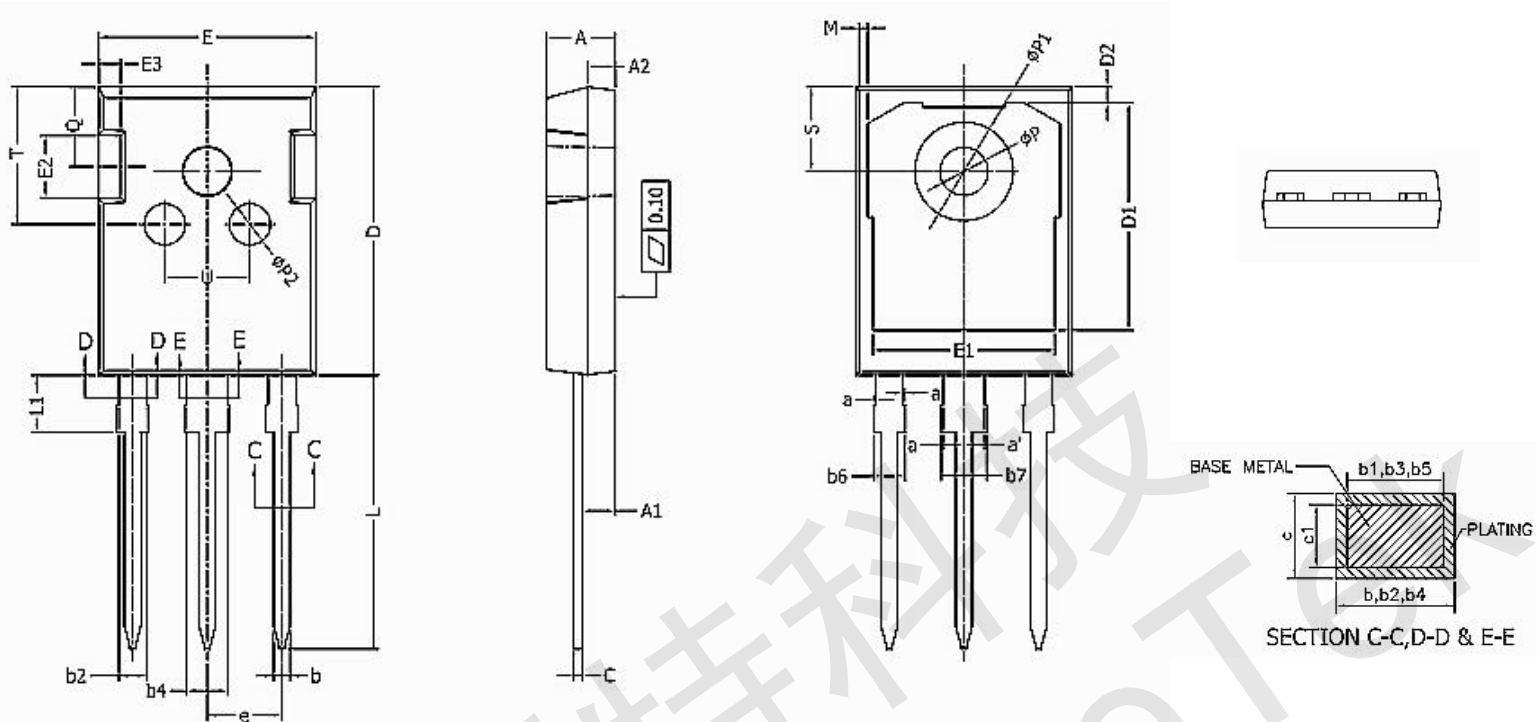
Unit:mm			
Symbol	Min.	Nom.	Max.
D1	5.20	--	--
E	6.50	6.60	6.70
E1	4.60	4.83	5.00
e	2.24	2.29	2.34
e1	4.47	4.57	4.67
H	16.18	16.48	16.78
L	9.00	9.30	9.60
L1	0.95	1.16	1.35
L2	0.90	1.08	1.25
$\theta 1$	3°	5°	7°
$\theta 2$	1°	3°	5°

Ordering information For TO-251

Package	Units/Tube	Tubes/ Inner Box	Units/Inner Box	Inner Box/Carton Box	Units/Carton Box
TO-251	75	120	9000	4	36000



TO-247



Unit:mm			
Symbol	Min.	Nom	Max.
A	4.90	5.00	5.10
A1	2.31	2.41	2.51
A2	1.90	2.00	2.10
a	0	---	0.15
a'	0	---	0.15
b	1.16	---	1.26
b1	1.15	1.2	1.22
b2	1.96	---	2.06
b3	1.95	2.00	2.02
b4	2.96	---	3.06
b5	2.96	3.00	3.02
b6	---	---	2.25
b7	---	---	3.25
c	0.59	---	0.66
c1	0.58	0.60	0.62
D	20.90	21.00	21.10
D1	16.25	16.55	16.85

Unit:mm			
Symbol	Min.	Nom.	Max.
D2	1.05	1.17	1.35
E	15.70	15.80	15.90
E1	13.10	13.30	13.50
E2	4.40	4.50	4.60
E3	2.40	2.50	2.60
e	5.436 BSC		
L	19.80	19.92	20.10
L1	---	---	4.30
M	0.35	---	0.95
P	3.40	3.50	3.60
P1	7.00	---	7.40
P2	2.40	2.50	2.60
Q	5.60	---	6.00
S	6.05	6.15	6.25
T	9.80	---	10.20
U	6.00	---	6.40

Ordering information For TO-247

Package	Units/Tube	Tubes/ Inner Box	Units/Inner Box	Inner Box/Carton Box	Units/Carton Box
TO-247	30	20	600	5	3000



Disclaimer

HRD has made reasonable commercial efforts to ensure that the information given in this datasheet is correct. However, it must clearly be understood that such information is for guidance only and does not constitute any representation or form part of any offer or contract.

For documents and material available from this datasheet, HRD does not warrant or assume any legal liability or responsibility for the accuracy, completeness, or usefulness of any information, product, technology or process disclosed hereunder.

HRD reserves the rights to at its own discretion to make any changes or improvements to this datasheet. Unless said datasheet is incorporated into the formal contract, any customer should not rely on the information as any specification or product parameters duly committed by HRD. Customers are hereby advised to verify that the information contained herein is current and complete before the entering of any contract or acknowledgement of any purchase order. Accordingly, all products specified hereunder shall be sold subject to HRD's terms and conditions supplied at the time of order acknowledgement. Except where agreed upon by contractual agreement, testing of all parameters of each product is not necessarily performed.

HRD does not warrant or convey any license either expressed or implied under its patent rights, nor the rights of others. Reproduction of information contained herein shall be only permissible if such reproduction is without any modification or alteration. Reproduction of this information with any alteration is an unfair and deceptive business practice. HRD is not responsible or liable for such altered documentation.

Resale of HRD's products with statements different from or beyond the parameters stated by HRD for that product or service voids all express or implied warranties for the associated HRD's product or service and is unfair and deceptive business practice. HRD is not responsible or liable for any such statements.

HRD's products are not authorized for use as critical components in life support devices or systems without the express written approval of HRD. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform, when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.